## SANMVOTH 2SK2909

## Features

- Low ON resistance.
- Ultrahigh-speed switching.
- 2.5 V drive


## Package Dimensions

unit:mm
2091A


## Absolute Maximum Ratings at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Drain-to-Source Voltage | $\mathrm{V}_{\mathrm{DSS}}$ |  | 20 | V |
| Gate-to-Source Voltage | $\mathrm{V}_{\mathrm{GSS}}$ |  | $\pm 10$ | V |
| Drain Current (DC) | $\mathrm{I}_{\mathrm{D}}$ |  | 0.8 | A |
| Drain Current (Pulse) | $\mathrm{I}_{\mathrm{DP}}$ | $\mathrm{PW} \leq 10 \mu \mathrm{~s}$, duty cycle $\leq 1 \%$ | 3.2 | A |
| Allowable Power Dissipation | $\mathrm{P}_{\mathrm{D}}$ |  | 0.25 | W |
| Channel Temperature | Tch |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | Tstg |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| Drain-to-Source Breakdown Voltage | $\mathrm{V}_{\text {(BR) } \mathrm{DSS}}$ | ${ }^{\mathrm{D}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0$ | 20 |  |  | V |
| Zero Gate Voltage Drain Current | IDSS | $\mathrm{V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0$ |  |  | 10 | $\mu \mathrm{A}$ |
| Gate-to-Source Leakage Current | IGSS | $\mathrm{V}_{\mathrm{GS}}= \pm 8 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Cutoff Voltage | $\mathrm{V}_{\mathrm{GS}}$ (off) | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}$ | 0.4 |  | 1.3 | V |
| Forward Transfer Admittance | \| yfs | | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=400 \mathrm{~mA}$ | 1.4 | 2 |  | S |
| Static Drain-to-Source On-State Resistance | RDS(on)1 | $\mathrm{I}_{\mathrm{D}}=400 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=4 \mathrm{~V}$ |  | 200 | 300 | $\mathrm{m} \Omega$ |
|  | RDS(on)2 | $\mathrm{I}_{\mathrm{D}}=100 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |  | 300 | 480 | $\mathrm{m} \Omega$ |

Marking: DK
Continued on next page.

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| Parameter | Symbol | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| Input Capacitance | Ciss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 90 |  | pF |
| Output Capacitance | Coss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 60 |  | pF |
| Reverse Transfer Capacitance | Crss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 28 |  | pF |
| Turn-ON Delay Time | $\mathrm{t}_{\mathrm{d}(\mathrm{on})}$ | See specified Test Circuit |  | 10 |  | ns |
| Rise Time | $\mathrm{t}_{\mathrm{r}}$ | See specified Test Circuit |  | 15 |  | ns |
| Turn-OFF Delay Time | $\mathrm{t}_{\mathrm{d} \text { (off) }}$ | See specified Test Circuit |  | 25 |  | ns |
| Fall Time | $\mathrm{t}_{\mathrm{f}}$ | See specified Test Circuit |  | 20 |  | ns |
| Total Gate Charge | Qg | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=800 \mathrm{~mA}$ |  | 6 |  | nC |
| Gate-to-Source Charge | Qgs |  |  | 1 |  | nC |
| Gate-to-Drain "Miller" Charge | Qgd |  |  | 2 |  | nC |
| Diode Forward Voltage | $\mathrm{V}_{\text {SD }}$ | $\mathrm{I}_{\mathrm{S}}=800 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0$ |  | 0.8 | 1.2 | V |

## Switching Time Test Circuit




Ciss,Coss,Crss - VDS


SW Time - ID




VGS - Qg


A S O

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